





Compelling performance for high-end applications

Transcend's PCIe SSD 110S follows NVMe 1.3 and utilizes the PCIe[™] Gen3 x4 interface, meaning four lanes are used for transmitting and receiving data simultaneously, resulting in compelling performance of up to 1,700MB/s read and 1,400MB/s write. Note: Performance is based on CrystalDiskMark v5.0.2.



Understanding the PCIe interface

PCIe (or PCI Express®) is a much faster interface than SATA (or Serial ATA) for connecting a host computer to solid-state storage devices over one or more lanes consisting of one transmit and one receive serial interface in each lane, meaning it can better fulfill new performance requirements.



Understanding the NVMe standard

NVMe (or NVM Express®) is a host controller interface standard designed to address the needs of enterprise and client applications that utilize PCI Express-based solid-state storage. NVMe calls for better performance vectors than AHCI (Advanced Host Controller Interface), including scalable bandwidth, increased IOPS, and low latency.





PCIe M.2 SSDs

PCIe SSD 110S

Features

- Adopts PCle Gen3 x4 interface and NVMe
 1.3 standard
- · Up to 1,700 MB/s read; 1,400 MB/s write
- · 3D NAND flash memory
- Engineered with LDPC (Low-Density Parity Check) coding to ensure data integrity; built-in SLC caching technology for exceptional transfer speeds
- Engineered dynamic thermal throttling mechanism

Transcend

SSD Scope Software

Transcend SSD Scope is advanced, user-friendly software that makes it easy to ensure your Transcend SSD remains healthy, and continues to run fast and error-free by determining the condition and optimizing the performance of your drive.

Specification

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Dimensions	128GB-256GB: 80 mm x 22 mm x 2.23 mm (3.15" x 0.87" x
	0.09")
	512GB-1TB: 80 mm x 22 mm x 3.58 mm (3.15" x 0.87" x 0.14")
Weight	8 g (0.28 oz)
M.2 Type	2280-D2-M (Double-sided)
	2280-S2-M (Single-sided)

Interface

Bus Interface NVMe PCle Gen3 x4

Storage

201486	
Flash Type	3D NAND flash
Capacity	128 GB / 256 GB / 512 GB / 1 TB

Operating Environment

Operating Temperature	0°C (32°F) ~ 70°C (158°F)
Operating Voltage	3.3V±5%

Performance

Sequential Read/Write (CrystalDiskMark)	Read: 1,700 MB/s Write: 1,400 MB/s
4K Random Read/Write (IOmeter)	Read: 160,000 IOPS Write: 140,000 IOPS
Mean Time Between Failures (MTBF)	2,000,000 hour(s)
Terabytes Written (TBW)	400 TBW
Drive Writes Per Day (DWPD)	0.2 (5 yrs)

Warranty

Certificate	CE/FCC/BSMI/KC/RCM
Warranty	Five-year Limited Warranty

Note

1. Speed may vary due to host hardware, software, usage, and storage capacity.

Ordering Information

128GB	TS128GMTE110S
256GB	TS256GMTE110S
512GB	TS512GMTE110S
1TB	TS1TMTE110S